

Absolute maximum ratings

(Ta=25°C)

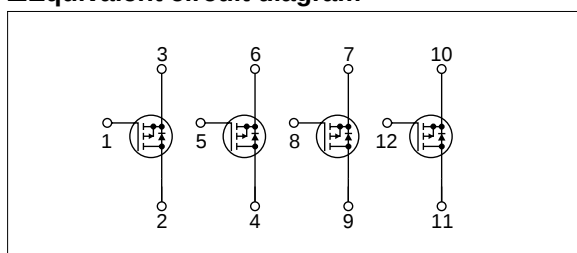
Symbol	Ratings	Unit
V_{DSS}	-100	V
V_{GSS}	± 20	V
I_D	± 5	A
$I_{D(pulse)}$	± 10 (PW ≤ 1 ms)	A
P_T	5 (Ta=25°C, with all circuits operating, without heatsink)	W
	35 (Tc=25°C, with all circuits operating, with infinite heatsink)	W
θ_{j-a}	25 (Junction-Air, Ta=25°C, with all circuits operating)	°C/W
θ_{j-c}	3.57 (Junction-Case, Tc=25°C, with all circuits operating)	°C/W
V_{ISO}	1000 (Between fin and lead pin, AC)	Vrms
Tch	150	°C
Tstg	-40 to +150	°C

Electrical characteristics

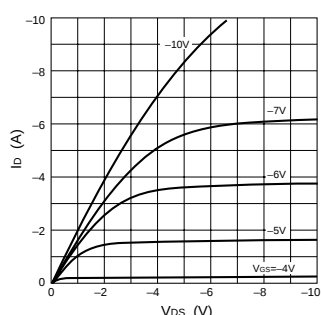
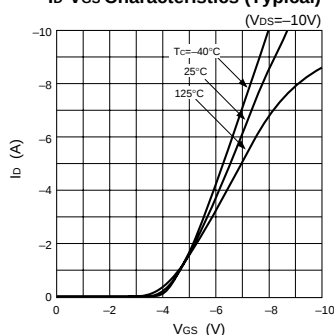
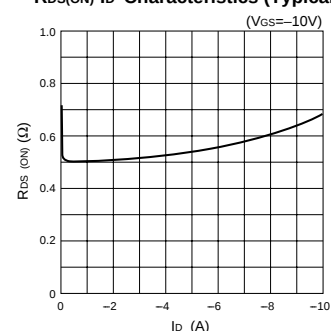
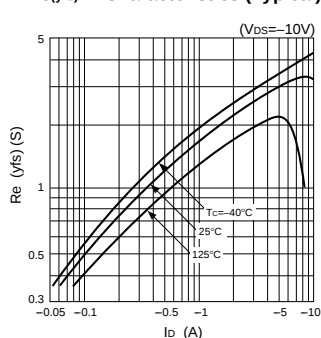
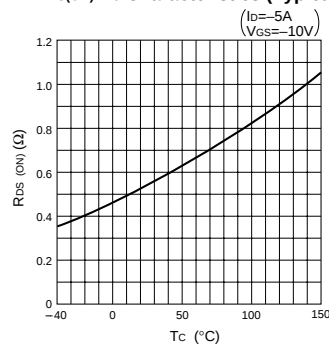
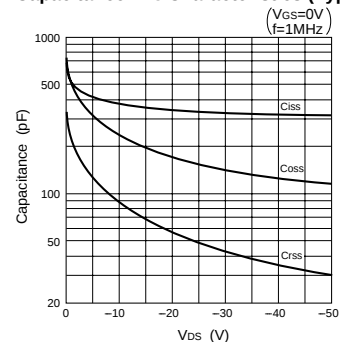
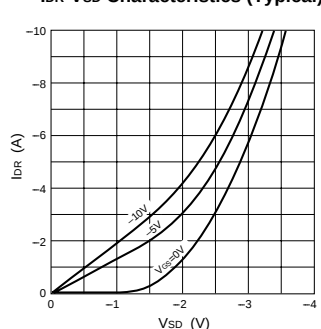
(Ta=25°C)

Symbol	Specifications			Unit	Condition
	min	typ	max		
$V_{(BR)DSS}$	-100			V	$I_D = -250\mu A$, $V_{GS} = 0V$
I_{GSS}			± 500	nA	$V_{GS} = \pm 20V$
I_{DSS}			-250	μA	$V_{DS} = -100V$, $V_{GS} = 0V$
V_{TH}	-2.0		-4.0	V	$V_{DS} = -10V$, $I_D = -250\mu A$
$R_{e(yfs)}$	0.9	2.0		S	$V_{DS} = -10V$, $I_D = -5A$
$R_{DS(ON)}$		0.55	0.7	Ω	$V_{GS} = -10V$, $I_D = -5A$
C_{iss}		300		pF	$V_{DS} = -25V$, $f = 1.0MHz$, $V_{GS} = 0V$
C_{oss}		200		pF	
t_{on}		150		ns	$I_D = -5A$, $V_{DD} = -50V$, $V_{GS} = -10V$, see Fig. 4 on page 16.
t_{off}		200		ns	
V_{SD}		-4.5	-5.5	V	$I_{SD} = -5A$, $V_{GS} = 0V$
t_{rr}		220		ns	$I_{SD} = \pm 100mA$

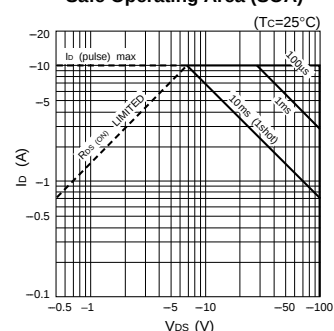
Equivalent circuit diagram



Characteristic curves

 I_D - V_{DS} Characteristics (Typical) I_D - V_{GS} Characteristics (Typical) $R_{DS(ON)}$ - I_D Characteristics (Typical) $R_{e(yfs)}$ - I_D Characteristics (Typical) $R_{DS(ON)}$ - T_C Characteristics (Typical)Capacitance- V_{DS} Characteristics (Typical) I_{DR} - V_{SD} Characteristics (Typical)

Safe Operating Area (SOA)

 P_T - T_a Characteristics